











CSD23202W10

SLPS506 - AUGUST 2014

CSD23202W10 12-V P-Channel NexFET™ Power MOSFET

Features

- Ultra-Low Qa and Qad
- Small Footprint 1 mm x 1 mm
- Low Profile 0.62-mm Height
- Pb Free
- Gate ESD Protection 3 kV
- **RoHS Compliant**
- Halogen Free

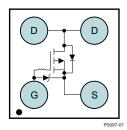
Applications

- **Battery Management**
- Load Switch
- **Battery Protection**

Description

This 12 V, 44 m Ω device is designed to deliver the lowest on-resistance and gate charge in a small 1 mm x 1 mm outline with excellent thermal characteristics in an ultra-low profile.

Top View



Product Summary

$T_A = 25^\circ$	С	TYPICAL VAL	UNIT			
V_{DS}	Drain-to-Source Voltage -12					
Q_g	Gate Charge Total (-4.5 V)	2.9	nC			
Q_{gd}	Gate Charge Gate-to-Drain	0.28	nC			
R _{DS(on)}		$V_{GS} = -1.5 \text{ V}$	82	mΩ		
	Drain-to-Source On-	$V_{GS} = -1.8 \text{ V}$	67	mΩ		
	Resistance	$V_{GS} = -2.5 \text{ V}$	54	mΩ		
		V _{GS} = -4.5 V	44	mΩ		
$V_{GS(th)}$	Threshold Voltage	-0.60	•	٧		

Ordering Information(1)

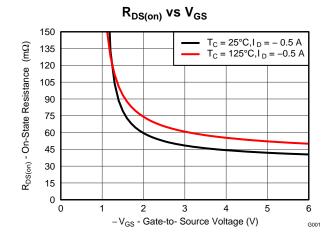
Device	Qty	Media	Package	Ship					
CSD23202W10	3000	7-Inch Reel	1 x 1-mm Wafer	Tape and					
CSD23202W10T	250	7-Inch Reel	Level Package	Reel					

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 2$	5°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	-12	V
V_{GS}	Gate-to-Source Voltage	-6	V
I_D	Continuous Drain Current ⁽¹⁾	-2.2	Α
I _{DM}	Pulsed Drain Current ⁽²⁾	-25	Α
	Continuous Gate Clamp Current	-0.5	Α
I _G	Pulsed Gate Clamp Current	-7	Α
P _D	Power Dissipation ⁽¹⁾	1	W
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	°C

- (1) Device operating at a temperature of 105°C
- (2) Typ R_{θJA} = 195°C/W, Pulse width ≤100 μs, duty cycle ≤1%



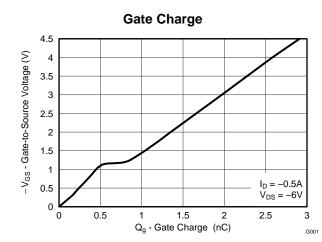






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4 Revision History

DATE	REVISION	NOTES
August 2014	*	Initial release.



5 Specifications

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5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

$(1_A = 25)$	°C unless otherwise stated)					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV_{DSS}	Drain-to-Source Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	-12			V
BV_GSS	Gate-to-Source Voltage;	$V_{DS} = 0 \text{ V}, I_{G} = -250 \mu\text{A}$	-6		-7.2	V
I _{DSS}	Drain-to-Source Leakage Current	$V_{GS} = 0 \text{ V}, V_{DS} = -9.6 \text{ V}$			-1	μΑ
I _{GSS}	Gate-to-Source Leakage Current	$V_{DS} = 0 \text{ V}, V_{GS} = -6 \text{ V}$			-100	nA
$V_{GS(th)}$	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_{D} = -250 \mu A$	-0.4	-0.6	-0.9	V
		$V_{GS} = -1.5 \text{ V}, I_D = -0.5 \text{ A}$		82	123	$m\Omega$
D	Drain-to-Source On-Resistance	$V_{GS} = -1.8 \text{ V}, I_D = -0.5 \text{ A}$		67	92	$m\Omega$
R _{DS(on)}	Diam-to-Source On-Resistance	$V_{GS} = -2.5 \text{ V}, I_D = -0.5 \text{ A}$		54	66	$m\Omega$
		$V_{GS} = -4.5 \text{ V}, I_D = -0.5 \text{ A}$		44	53	mΩ
g_{fs}	Transconductance	$V_{DS} = -1.2 \text{ V}, I_{D} = -0.5 \text{ A}$		5.6		S
DYNAMI	IC CHARACTERISTICS					
C _{ISS}	Input Capacitance			394	512	рF
Coss	Output Capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = -6.0 \text{ V}, f = 1 \text{ MHz}$		238	310	pF
C _{RSS}	Reverse Transfer Capacitance			29	37	pF
Q_g	Gate Charge Total (-4.5 V)			2.9	3.8	nC
Q_{gd}	Gate Charge Gate-to-Drain	$V_{DS} = -6 \text{ V}, I_{D} = -0.5 \text{ A}$		0.28		nC
Q_{gs}	Gate Charge Gate-to-Source	$V_{DS} = -6 \text{ V}, I_{D} = -0.5 \text{ A}$		0.55		nC
Q _{g(th)}	Gate Charge at V _{th}			0.29		nC
Q _{OSS}	Output Charge	$V_{DS} = -6 \text{ V}, V_{GS} = 0 \text{ V}$		2.0		nC
t _{d(on)}	Turn On Delay Time			9		ns
t _r	Rise Time	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V},$		4		ns
t _{d(off)}	Turn Off Delay Time	$I_D = -0.5 \text{ A R}_G = 0 \Omega$		58		ns
t_f	Fall Time			21		ns
DIODE C	CHARACTERISTICS		•		,	
V _{SD}	Diode Forward Voltage	$I_S = -0.5 \text{ A}, V_{GS} = 0 \text{ V}$		-0.66	-1	V
Q _{rr}	Reverse Recovery Charge	V 6 V I 0 5 A di/dt 400 A/··-		3.7		nC
t _{rr}	Reverse Recovery Time	$V_{DS} = -6 \text{ V}, I_F = -0.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		12		ns

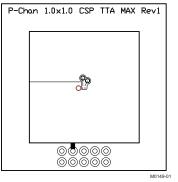
5.2 Thermal Information

(T_A = 25°C unless otherwise stated)

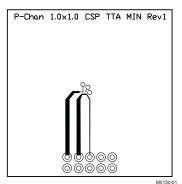
	THERMAL METRIC	MIN	TYP	MAX	UNIT
D	Junction-to-Ambient Thermal Resistance ⁽¹⁾				°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance (2)		65		C/VV

 ⁽¹⁾ Device mounted on FR4 material with minimum Cu mounting area.
 (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.





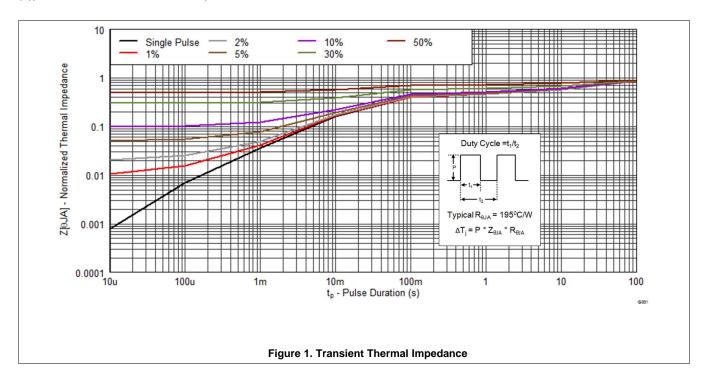
Typical $R_{\theta JA} = 65^{\circ}\text{C/W}$ when mounted on 1 inch² of 2 oz. Cu.



Typical $R_{\theta JA} = 195^{\circ}\text{C/W}$ when mounted on minimum pad area of 2 oz. Cu.

5.3 Typical MOSFET Characteristics

(T_A = 25°C unless otherwise stated)

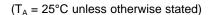


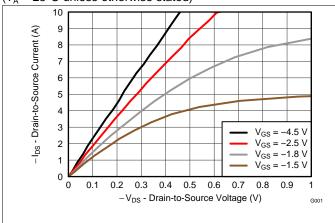
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Typical MOSFET Characteristics (continued)





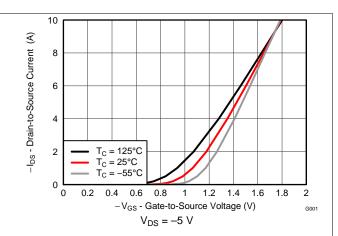


Figure 2. Saturation Characteristics

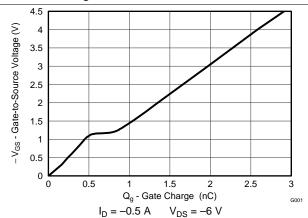


Figure 3. Transfer Characteristics

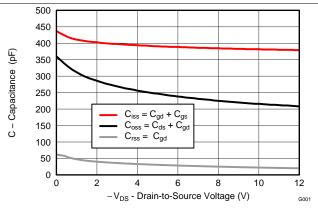


Figure 4. Gate Charge

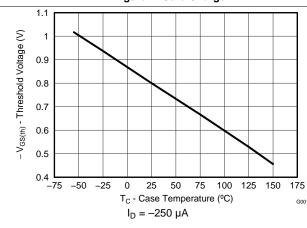


Figure 5. Capacitance

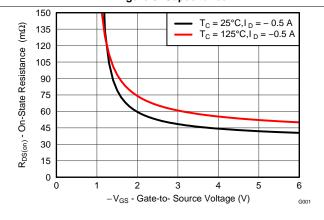


Figure 6. Threshold Voltage vs Temperature

Figure 7. On-State Drain-to-Source Resistance vs Gate-to-Source Voltage

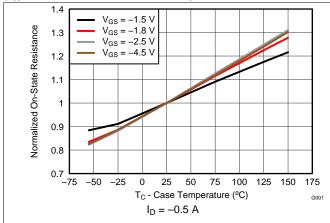
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Typical MOSFET Characteristics (continued)

(T_A = 25°C unless otherwise stated)



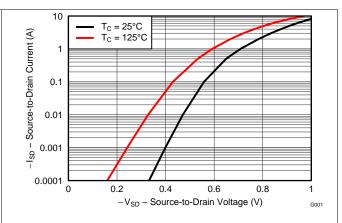
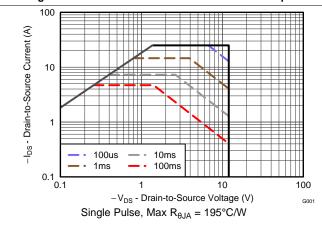


Figure 8. Normalized On-State Resistance vs Temperature





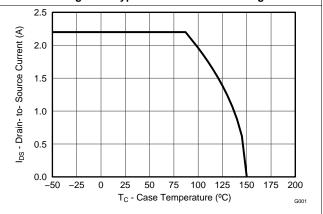


Figure 10. Maximum Safe Operating Area

Figure 11. Maximum Drain Current vs Temperature

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6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

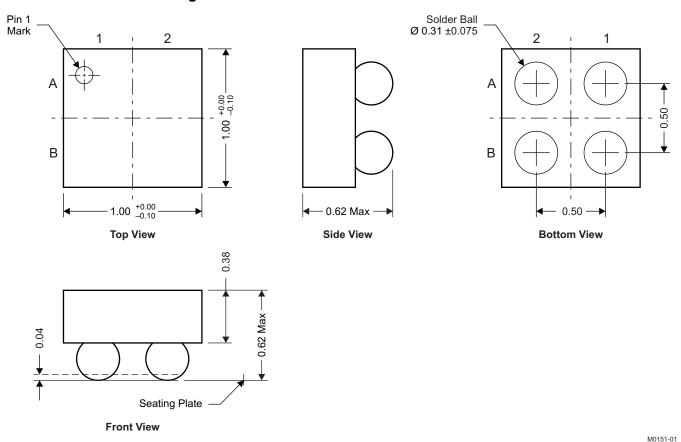
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TEXAS INSTRUMENTS

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 CSD23202W10 Package Dimensions



NOTE: All dimensions are in mm (unless otherwise specified).

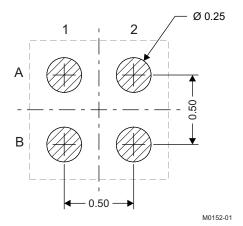
Pin Configuration Table

POSITION	DESIGNATION
B1	Source
A1	Gate
A2. B2	Drain



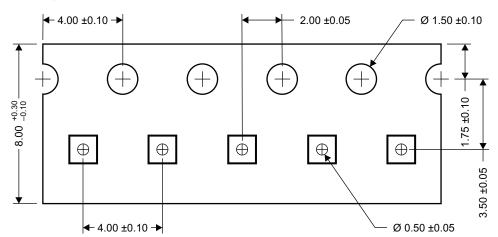
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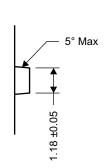
7.2 Land Pattern Recommendation

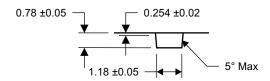


NOTE: All dimensions are in mm (unless otherwise specified).

7.3 Tape and Reel Information







M0153-01

NOTE: All dimensions are in mm (unless otherwise specified).



PACKAGE OPTION ADDENDUM

29-Jun-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD23202W10	ACTIVE	DSBGA	YZB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		202	Samples
CSD23202W10T	ACTIVE	DSBGA	YZB	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-55 to 150	202	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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